

# Aligned with global growth

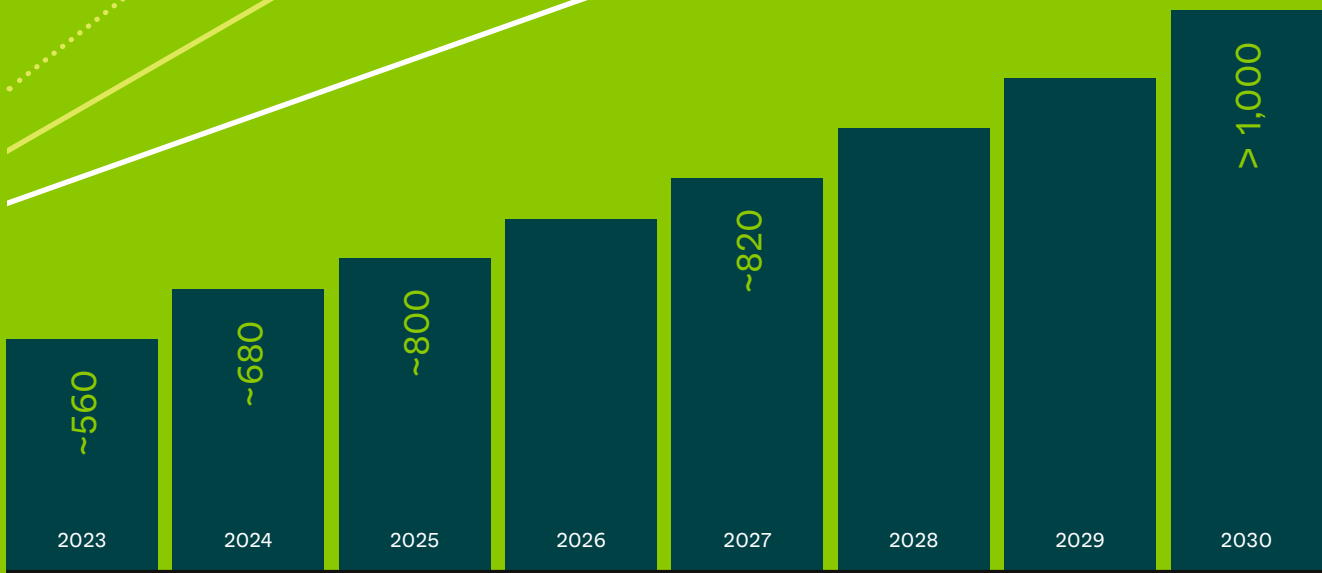
VAT benefits from exposure to the secular growth story in the semiconductor market. Shrinking node sizes also allow VAT to outgrow market trends.

**Growth factor 3:**  
Increasingly complex manufacturing

**Growth factor 2:**  
Evolving manufacturing technology

**Growth factor 1:**  
Data society

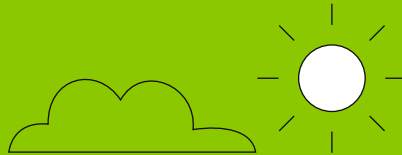
Semiconductor market to reach  
**> one trillion**  
USD by 2030



Size of semiconductor market, 2023 to 2030 (USD billion)  
Source: TechInsights (December 2024)

# Imagine a semiconductor chip as a small city with high-rise buildings.

Shrinking node sizes and new architectures require more advanced etch and deposition tools.



You can only etch/  
depo buildings with  
a flat side.

You can also etch/  
depo the balconies  
of each high-rise.

You can etch/depo  
multiple buildings at  
the same time.

Up to 2024

2025 onwards

2032 onwards

**FinFET**  
(early 3D structure)

**GAA**  
(1<sup>st</sup> fully 3D structure)

**CFET**  
(stacking structure)

Current transistor structure has replaced CMOS structures thanks to superior switching times and density.

Gate all-around transistors are successors to FinFET. Here, logic gates surround the channel on all sides, allowing smaller node sizes and higher performance.

Below 1nm, CFET will be the transistor structure that allows channel width to be maximized going forward.